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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/863,737	05/23/2001	Noriaki Oda	12562A	1794

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[REDACTED] EXAMINER

LEWIS, MONICA

[REDACTED] ART UNIT

[REDACTED] PAPER NUMBER

2822

DATE MAILED: 03/20/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	09/863,737	ODA ET AL.
	Examiner	Art Unit
	Monica Lewis	2822

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

**A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM
 THE MAILING DATE OF THIS COMMUNICATION.**

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) Responsive to communication(s) filed on 03 January 2003.
- 2a) This action is **FINAL**. 2b) This action is non-final.
- 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1,3-5,7 and 8 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) Claim(s) _____ is/are allowed.
- 6) Claim(s) 1,3-5,7 and 8 is/are rejected.
- 7) Claim(s) _____ is/are objected to.
- 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
- 10) The drawing(s) filed on 23 May 2001 is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) The proposed drawing correction filed on _____ is: a) approved b) disapproved by the Examiner.
 If approved, corrected drawings are required in reply to this Office action.
- 12) The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

- 13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) All b) Some * c) None of:
1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. 09/275,532.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.
- 14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
 a) The translation of the foreign language provisional application has been received.
- 15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

- | | |
|----------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) Paper No(s). _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

1. This action is in response to the amendment filed January 3, 2003.

Claim Objections

2. Claim 3 is objected to because of the following informalities: a) it is dependent upon itself. Appropriate correction is required.

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 1, 3, 5 and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's Admitted Prior Art Figures in view of Usami et al. (Japanese Publication No. 10-056009).

In regards to claims 1 and 5, Applicant's Admitted Prior Art discloses the following:

- a) a semiconductor device having a plurality of wirings (8, 15, 20) juxtaposed with one another (See Figure 1); and
- b) a SiOF insulating film (4,12,17) being in contact with the wirings (See Figure 1).

In regards to claims 1 and 5, Applicant's Admitted Prior Art fails to disclose the following:

- a) the fluorine concentration of the SiOF insulating film at a wiring gap portion is set to be higher than the fluorine concentration of the SiOF insulating film on the upper side of the wirings.

However, Usami et al. (“Usami”) discloses a semiconductor device where the fluorine concentration of the SiOF at the wiring gap is higher than the concentration of the insulating film on the upper side of wirings (See Abstract and Paragraph 40). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor device of Applicant’s Admitted Prior Art to include a higher fluorine concentration of SiOF at the wiring gap than the concentration of the insulating film on the wirings as disclosed in Usami because it reduces the capacitance among the wiring therefore resulting in a high operating speed (See Abstract and Paragraph 40).

Additionally, since Applicant’s Admitted Prior Art and Usami are both from the same field of endeavor, the purpose disclosed by Usami would have been recognized in the pertinent art of Applicant’s Admitted Prior Art.

In regards to claims 3 and 7, Applicant’s Admitted Prior Art fails to disclose the following:

a) thickness of the first SiOF film at a center of the wiring gap portion is within the range of 1/3 to 1/1 times of the thickness of the wirings.

However, the applicant has not established the critical nature of the dimension of 1/3 to 1/1 times of the thickness. “The law is replete with cases in which the difference between the claimed invention and the prior art is some range or other variable within the claims. . . . In such a situation, the applicant must show that the particular range is critical, generally by showing that the claimed range achieves unexpected results relative to the prior art range.” *In re Woodruff*, 919 F.2d 1575, 16 USPQ2d 1934 (Fed. Cir. 1990).

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5. Claims 4 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant's Admitted Prior Art Figures in view of Usami et al. (Japanese Publication No. 10-056009) and Nishiyama et al. (U.S. Patent No. 5,429,995).

In regards to claims 4 and 8, Applicant's Admitted Prior Art fails to disclose the following:

a) fluorine concentration of the first SiOF film is set to 5 atom % or more, and the fluorine concentration of the second SiOF film is set to be less than 5 atom %.

However, Nishiyama et al. ("Nishiyama") discloses a semiconductor device where the fluorine concentration of SiOF is greater and lesser than 5 atom % (See Column 4 Lines 30-32). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor device of Applicant's Admitted Prior Art to include SiOF where the fluorine concentration is greater and lesser than 5 atom % as disclosed in Nishiyama because it manipulates the power consumption and operating speed of the system (See Column 3 Lines 44-56 and Column 4 Lines 30-32).

Additionally, since Applicant's Admitted Prior Art and Nishiyama are both from the same field of endeavor, the purpose disclosed by Nishiyama would have been recognized in the pertinent art of Applicant's Admitted Prior Art.

Response to Arguments

6. Applicant's arguments filed January 3, 2003 have been fully considered but they are not persuasive. Applicant argues the following: a) "the applicant's admitted prior art does not teach, disclose or suggest that the fluorine concentration at the wiring gap portion is higher than the fluorine concentration of the SiOF insulating film on the wirings;" b) "the higher fluorine film of the present invention contacts only the wire gap area and not the upper side of the wiring;" and c)

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“Claim 1 recites a device with one layer containing a plurality of wirings, Claim 5 recites a device with a plurality of wiring layers.” However, Usami discloses a semiconductor device where the fluorine concentration of the SiOF at the wiring gap is higher than the concentration of the insulating film on the upper side of wirings (See Drawing 1b, Abstract and Section 40). Additionally, “the higher fluorine film of the present invention contacts only the wire gap area and not the upper side of the wiring” limitation is not present in the claims. Finally, there is nothing in Claim 1 that indicates that there is only one layer containing a plurality of wirings.

Conclusion

7. Applicant is advised that should claim 1 be found allowable, claim 5 will be objected to under 37 CFR 1.75 as being a substantial duplicate thereof. When two claims in an application are duplicates or else are so close in content that they both cover the same thing, despite a slight difference in wording, it is proper after allowing one claim to object to the other as being a substantial duplicate of the allowed claim. See MPEP § 706.03(k).

8. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

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however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Monica Lewis whose telephone number is 703-305-3743. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 703-308-4905. The fax phone number for the organization where this application or proceeding is assigned is 703-308-7722 for regular and after final communications. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

ML
March 12, 2003



AMIR ZARABIAN
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